PNP Silicon Epitaxial Planar Transistor

For switching and general purpose applications.

The transistor is subdivided into three groups O, Y and G, according to its DC current gain.



1. Base 2. Emitter 3. Collector

SOT-23 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

	Symbol	Value	Unit
Collector Emitter Voltage	-V _{CEO}	50	V
Collector Base Voltage	-V _{CBO}	50	V
Emitter Base Voltage	-V _{EBO}	5	V
Collector Current	-I _C	150	mA
Base Current	-I _B	30	mA
Power Dissipation	P _{tot}	200	mW
Junction Temperature	Tj	150	°C
Storage Temperature Range	Ts	-55 to +150	°C







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Characteristics at T_{amb}=25 °C

	Symbol	Min.	Тур.	Max.	Unit
DC Current Gain					
at -V _{CE} =6V, -I _C =2mA					
Current Gain Group O	h_{FE}	70	-	140	-
Y	h_{FE}	120	-	240	-
G	h_{FE}	200	-	400	-
Collector Cutoff Current					
at -V _{CB} =50V	-I _{CBO}	-	-	0.1	μA
Emitter Cutoff Current					
at -V _{EB} =5V	-I _{EBO}	-	-	0.1	μA
Collector Saturation Voltage					
at -I _C =100mA, -I _B =10mA	$-V_{CE(sat)}$	-	-	0.3	V
Transition Frequency					
at -V _{CE} =10V, -I _C =1mA	f⊤	80	-	-	MHz
Collector Output Capacitance					
at -V _{CB} =10V, f=1MHz	C _{OB}	-	4	7	pF
Noise Figure					
at -V _{CE} =6V, -I _C =0.1mA, f=1KHz, R _G =10K Ω	NF	-	1	10	dB

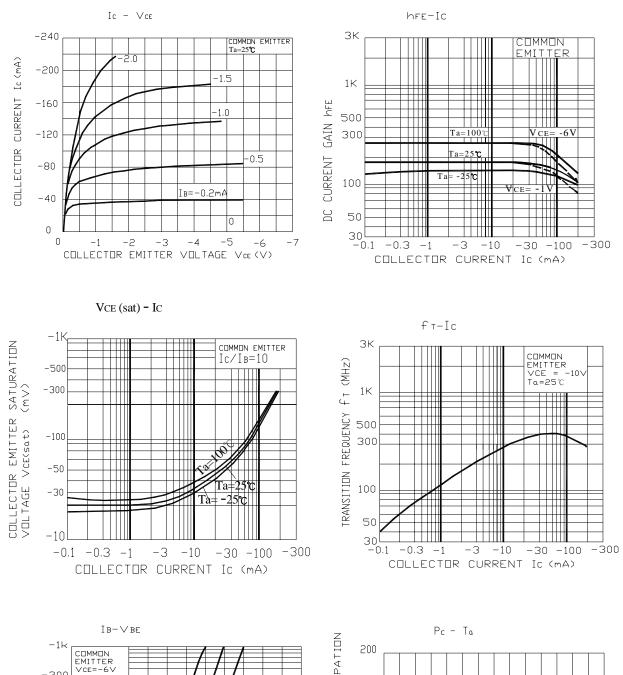


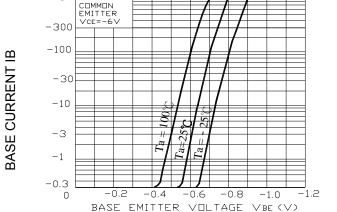


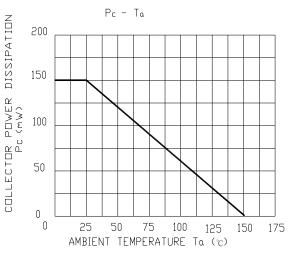


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